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# SS9012

### 1W Output Amplifier of Potable Radios in **Class B Push-pull Operation.**

- High total power dissipation. (P<sub>T</sub>=625mW)
- High Collector Current. (I<sub>C</sub>= -500mA)
   Complementary to SS9013
- Excellent h<sub>FE</sub> linearity.



1. Emitter 2. Base 3. Collector

# **PNP Epitaxial Silicon Transistor**

### Absolute Maximum Ratings Ta=25°C unless otherwise noted

| Symbol           | Parameter                   | Ratings   | Units |
|------------------|-----------------------------|-----------|-------|
| $V_{CBO}$        | Collector-Base Voltage      | -40       | V     |
| V <sub>CEO</sub> | Collector-Emitter Voltage   | -20       | V     |
| V <sub>EBO</sub> | Emitter-Base Voltage        | -5        | V     |
| I <sub>C</sub>   | Collector Current           | -500      | mA    |
| P <sub>C</sub>   | Collector Power Dissipation | 625       | mW    |
| T <sub>J</sub>   | Junction Temperature        | 150       | °C    |
| T <sub>STG</sub> | Storage Temperature         | -55 ~ 150 | °C    |

# **Electrical Characteristics** $T_a$ =25°C unless otherwise noted

| Symbol                | Parameter                            | Test Condition                              | Min. | Тур.  | Max. | Units |
|-----------------------|--------------------------------------|---------------------------------------------|------|-------|------|-------|
| BV <sub>CBO</sub>     | Collector-Base Breakdown Voltage     | $I_C = -100 \mu A, I_E = 0$                 | -40  |       |      | V     |
| BV <sub>CEO</sub>     | Collector-Emitter Breakdown Voltage  | $I_{C} = -1 \text{mA}, I_{B} = 0$           | -20  |       |      | V     |
| BV <sub>EBO</sub>     | Emitter-Base Breakdown Voltage       | $I_E = -100 \mu A, I_C = 0$                 | -5   |       |      | V     |
| I <sub>CBO</sub>      | Collector Cut-off Current            | $V_{CB} = -25V, I_{E} = 0$                  |      |       | -100 | nA    |
| I <sub>EBO</sub>      | Emitter Cut-off Current              | $V_{EB} = -3V, I_{C} = 0$                   |      |       | -100 | nA    |
| h <sub>FE1</sub>      | DC Current Gain                      | $V_{CE} = -1V, I_{C} = -50mA$               | 64   | 120   | 202  |       |
| $h_{FE2}$             |                                      | $V_{CE} = -1V, I_{C} = -500 \text{mA}$      | 40   | 90    |      |       |
| V <sub>CE</sub> (sat) | Collector-Emitter Saturation Voltage | $I_C = -500 \text{mA}, I_B = -50 \text{mA}$ |      | -0.18 | -0.6 | V     |
| V <sub>BE</sub> (sat) | Base-Emitter Saturation Voltage      | $I_C = -500 \text{mA}, I_B = -50 \text{mA}$ |      | -0.95 | -1.2 | V     |
| V <sub>BE</sub> (on)  | Base-Emitter On Voltage              | $V_{CE} = -1V, I_{C} = -10mA$               | -0.6 | -0.67 | -0.7 | V     |

### **h**<sub>FE</sub> Classification

| Classification   | D       | E        | F        | G         | Н         |
|------------------|---------|----------|----------|-----------|-----------|
| h <sub>FE1</sub> | 64 ~ 91 | 78 ~ 112 | 96 ~ 135 | 112 ~ 166 | 144 ~ 202 |

Rev. A4, November 2002

# **Typical Characteristics**

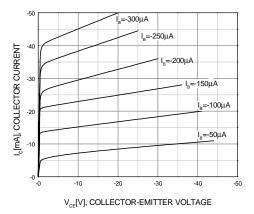


Figure 1. Static Characteristic

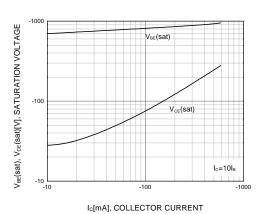
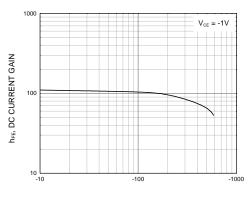


Figure 3. Base-Emitter Saturation Voltage Collector-Emitter Saturation Voltage



I<sub>C</sub>[mA], COLLECTOR CURRENT

Figure 2. DC current Gain

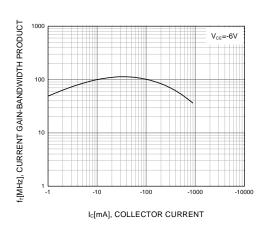
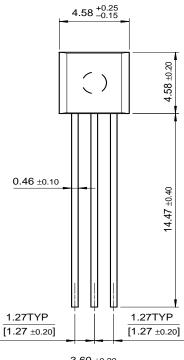


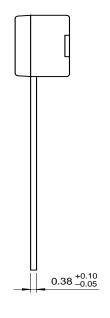
Figure 4. Current Gain Bandwidth Product

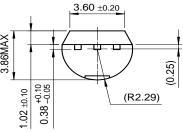
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# **Package Dimensions**

TO-92







Dimensions in Millimeters

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| ActiveArray™                      | FACT Quiet series™             | ISOPLANAR™             | $POP^{TM}$               | Stealth™              |
| Bottomless™                       | FAST <sup>®</sup>              | LittleFET™             | Power247™                | SuperSOT™-3           |
| CoolFET™                          | FASTr™                         | MicroFET™              | PowerTrench <sup>®</sup> | SuperSOT™-6           |
| $CROSSVOLT^{TM}$                  | FRFET™                         | MicroPak™              | QFET™                    | SuperSOT™-8           |
| DOME™                             | GlobalOptoisolator™            | MICROWIRE™             | QS <sup>TM</sup>         | SyncFET™              |
| EcoSPARK™                         | GTO™                           | MSX™                   | QT Optoelectronics™      | TinyLogic™            |
| E <sup>2</sup> CMOS <sup>TM</sup> | HiSeC™                         | MSXPro™                | Quiet Series™            | TruTranslation™       |
| EnSigna™                          | I <sup>2</sup> C <sup>TM</sup> | OCXTM                  | RapidConfigure™          | UHC™                  |
| Across the board.                 | Around the world.™             | OCXPro™                | RapidConnect™            | UltraFET <sup>®</sup> |
| The Power Franchise™              |                                | OPTOLOGIC <sup>®</sup> | SILENT SWITCHER®         | $VCX^{TM}$            |
| Programmable Ad                   | ctive Droop™                   | OPTOPLANAR™            | SMART START™             |                       |

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|--------------------------|---------------------------|-----------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------|
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